

## 5.0 A H-Bridge

The 33886 is a monolithic H-Bridge ideal for fractional horsepower DC-motor and bi-directional thrust solenoid control. The IC incorporates internal control logic, charge pump, gate drive, and low  $R_{DS(ON)}$  MOSFET output circuitry. The 33886 is able to control continuous inductive DC load currents up to 5.0 A. Output loads can be pulse width modulated (PWM-ed) at frequencies up to 10 kHz.

A Fault Status output reports undervoltage, short-circuit, and overtemperature conditions. Two independent inputs control the two half-bridge totem-pole outputs. Two disable inputs force the H-Bridge outputs to tri-state (exhibit high-impedance).

The 33886 is parametrically specified over a temperature range of  $-40\text{ }^{\circ}\text{C} \leq T_A \leq 125\text{ }^{\circ}\text{C}$ ,  $5.0\text{ V} \leq V+ \leq 28\text{ V}$ . The IC can also be operated up to 40 V with derating of the specifications. The IC is available in a surface mount power package with exposed pad for heatsinking. This device is powered by SMARTMOS technology.

### Features

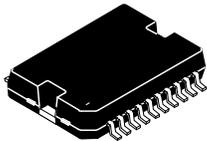
- 5.0 V to 40 V continuous operation
- 120 mΩ  $R_{DS(on)}$  H-Bridge MOSFETs
- TTL /CMOS compatible Inputs
- PWM frequencies up to 10 kHz
- Active current limiting via internal constant off-time PWM (with temperature-dependent threshold reduction)
- Output short-circuit protection
- Undervoltage shutdown
- Fault status reporting

33886

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H-BRIDGE

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VW SUFFIX (PB-FREE)  
98ASH70702A  
20-PIN HSOP

### Applications

- Automotive systems
- DC motor control in industrial and robotic systems
- DC motor and actuator control in boats, RVs, and marine systems
- Appliance and white goods electrical actuators
- Powered machine and hand tools
- Antenna rotors and dish positioning systems

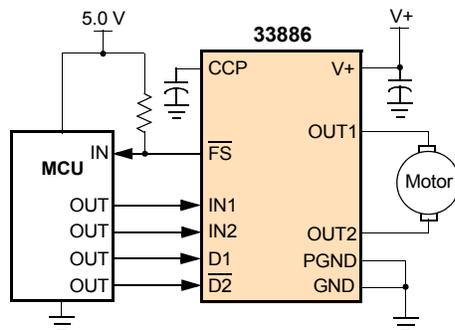


Figure 1. 33886 Simplified Application Diagram

# 1 Orderable Parts

**Table 1. Orderable Part Variations**

Part Number	Temperature (T <sub>A</sub> )	Package
MC33886PVW/R2	-40 to 125 °C	20 HSOP

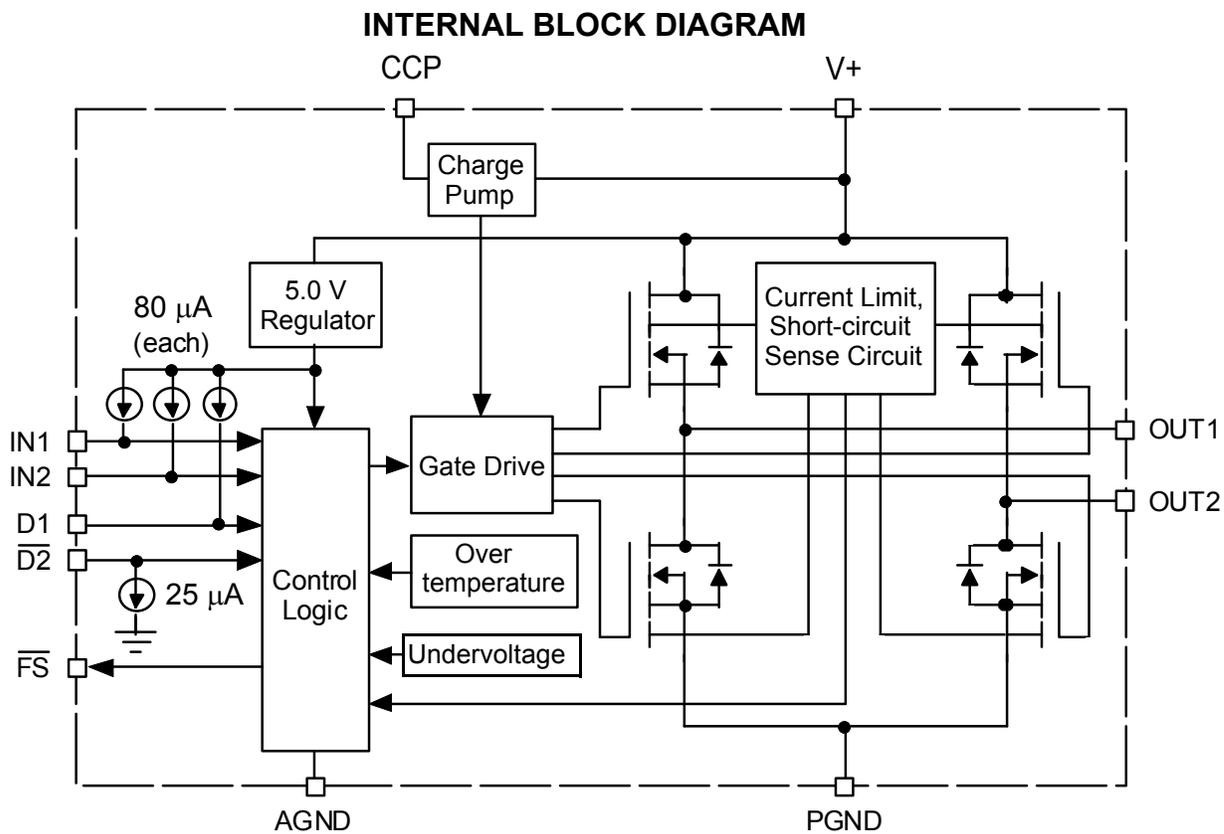
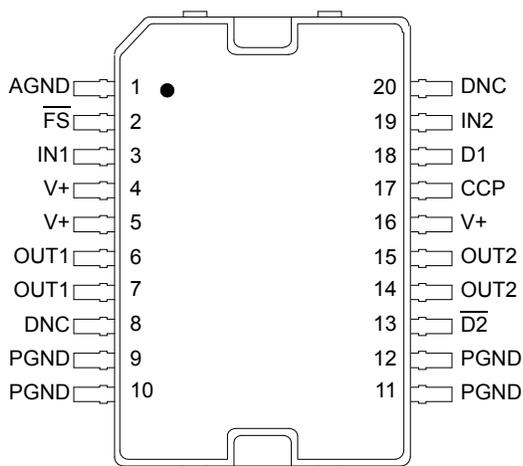


Figure 2. 33886 Simplified Internal Block Diagram

## PIN CONNECTIONS



**Figure 3. 33886 Pin Connections**

**Table 2. 33886 Pin Definitions**

A functional description of each pin can be found in the Functional Pin Description section beginning on [page 16](#).

Pin Number	Pin Name	Formal Name	Definition
1	AGND	Analog Ground	Low-current analog signal ground.
2	$\overline{\text{FS}}$	Fault Status for H-Bridge	Open drain active Low Fault Status output requiring a pull-up resistor to 5.0 V.
3	IN1	Logic Input Control 1	True logic input control of OUT1 (i.e., IN1 logic High = OUT1 logic High).
4, 5, 16	V+	Positive Power Supply	Positive supply connections.
6, 7	OUT1	H-Bridge Output 1	Output 1 of H-Bridge.
8, 20	DNC	Do Not Connect	Either do not connect (leave floating) or connect these pins to ground in the application. They are test mode pins used in manufacturing only.
9–12	PGND	Power Ground	Device high-current power ground.
13	$\overline{\text{D2}}$	Disable 2	Active Low input used to simultaneously tri-state disable both H-Bridge outputs. When $\overline{\text{D2}}$ is logic Low, both outputs are tri-stated.
14, 15	OUT2	H-Bridge Output 2	Output 2 of H-Bridge.
17	CCP	Charge Pump Capacitor	External reservoir capacitor connection for internal charge pump capacitor.
18	D1	Disable 1	Active High input used to simultaneously tri-state disable both H-Bridge outputs. When D1 is logic High, both outputs are tri-stated.
19	IN2	Logic Input Control 2	True logic input control of OUT2 (i.e., IN2 logic High = OUT2 logic High).

## ELECTRICAL CHARACTERISTICS

### MAXIMUM RATINGS

**Table 3. Maximum Ratings**

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Rating	Symbol	Value	Unit
Supply Voltage	V+	40	V
Input Voltage (1)	V <sub>IN</sub>	-0.1 to 7.0	V
$\overline{\text{FS}}$ Status Output (2)	V $\overline{\text{FS}}$	7.0	V
Continuous Current (3)	I <sub>OUT</sub>	5.0	A
ESD Voltage for VW Package			V
Human Body Model (4)	V <sub>ESD1</sub>	±2000	
Machine Model (5)	V <sub>ESD2</sub>	±200	
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C
Ambient Operating Temperature (6)	T <sub>A</sub>	-40 to 125	°C
Operating Junction Temperature	T <sub>J</sub>	-40 to 150	°C
Peak Package Reflow Temperature During Reflow (7), (8)	T <sub>PPRT</sub>	Note 7.	°C
Approximate Junction-to-Board Thermal Resistance (and Package Dissipation = 6.0 W) (9)	R <sub>θJB</sub>	~5.0	°C/W

**Notes**

- Exceeding the input voltage on IN1, IN2, D1, or  $\overline{\text{D2}}$  may cause a malfunction or permanent damage to the device.
- Exceeding the pull-up resistor voltage on the open drain  $\overline{\text{FS}}$  pin may cause permanent damage to the device.
- Continuous current capability so long as junction temperature is  $\leq 150^\circ\text{C}$ .
- ESD1 testing is performed in accordance with the Human Body Model ( $C_{ZAP} = 100 \text{ pF}$ ,  $R_{ZAP} = 1500 \Omega$ ).
- ESD2 testing is performed in accordance with the Machine Model ( $C_{ZAP} = 200 \text{ pF}$ ,  $R_{ZAP} = 0 \Omega$ ).
- The limiting factor is junction temperature, taking into account the power dissipation, thermal resistance, and heatsinking.
- Pin soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.
- Freescale's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), Go to [www.freescale.com](http://www.freescale.com), search by part number [e.g. remove prefixes/suffixes and enter the core ID to view all orderable parts. (i.e. MC33xxxD enter 33xxx), and review parametrics.
- Exposed heatsink pad plus the power and ground pins comprise the main heat conduction paths. The actual R<sub>θJB</sub> (junction-to-PC board) values will vary depending on solder thickness and composition and copper trace.

### STATIC ELECTRICAL CHARACTERISTICS

**Table 4. Static Electrical Characteristics**

Characteristics noted under conditions  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ , unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
<b>POWER SUPPLY</b>					
Operating Voltage Range <sup>(10)</sup>	$V_+$	5.0	–	40	V
Standby Supply Current $V_{EN} = 5.0\text{ V}$ , $I_{OUT} = 0\text{ A}$	$I_{Q(\text{standby})}$	–	–	20	mA
Threshold Supply Voltage					
Switch-OFF	$V_{+(\text{THRES-OFF})}$	4.15	4.4	4.65	V
Switch-ON	$V_{+(\text{THRES-ON})}$	4.5	4.75	5.0	V
Hysteresis	$V_{+(\text{HYS})}$	150	–	–	mV
<b>CHARGE PUMP</b>					
Charge Pump Voltage $V_+ = 5.0\text{ V}$ $8.0\text{ V} \leq V_+ \leq 40\text{ V}$	$V_{CP-V_+}$	3.35 –	– –	– 20	V
<b>CONTROL INPUTS</b>					
Input Voltage (IN1, IN2, D1, $\overline{D2}$ )					V
Threshold High	$V_{IH}$	3.5	–	–	
Threshold Low	$V_{IL}$	–	–	1.4	
Hysteresis	$V_{HYS}$	0.7	1.0	–	
Input Current (IN1, IN2, D1) <sup>(11)</sup> $V_{IN} = 0\text{ V}$	$I_{IN}$	-200	-80	–	$\mu\text{A}$
$\overline{D2}$ Input Current <sup>(12)</sup> $V_{\overline{D2}} = 5.0\text{ V}$	$I_{\overline{D2}}$	–	25	100	$\mu\text{A}$

**Notes**

- Specifications are characterized over the range of  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$ . Operation  $>28\text{ V}$  will cause some parameters to exceed listed min/max values. Refer to typical operating curves to extrapolate values for operation  $>28\text{ V}$  but  $\leq 40\text{ V}$ .
- Inputs IN1, IN2, and D1 have independent internal pull-up current sources.
- The  $\overline{D2}$  input incorporates an active internal pull-down current sink.

**Table 4. Static Electrical Characteristics**

Characteristics noted under conditions  $5.0\text{ V} \leq V+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ , unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
<b>POWER OUTPUTS (OUT1, OUT2)</b>					
Output-ON Resistance <sup>(13)</sup> $5.0\text{ V} \leq V+ \leq 28\text{ V}, T_J = 25^\circ\text{C}$ $8.0\text{ V} \leq V+ \leq 28\text{ V}, T_J = 150^\circ\text{C}$ $5.0\text{ V} \leq V+ \leq 8.0\text{ V}, T_J = 150^\circ\text{C}$	$R_{DS(ON)}$	–	120	–	m $\Omega$
Active Current Limiting Threshold (via Internal Constant OFF-Time PWM) <sup>(14)</sup>	$I_{LIM}$	5.2	6.5	7.8	A
High Side Short-circuit Detection Threshold	$I_{SCH}$	11	–	–	A
Low Side Short-circuit Detection Threshold	$I_{SCL}$	8.0	–	–	A
Leakage Current <sup>(15)</sup> $V_{OUT} = V+$ $V_{OUT} = GND$	$I_{OUT(LEAK)}$	–	100	200	$\mu\text{A}$
Output FET Body Diode Forward Voltage Drop <sup>(16)</sup> $I_{OUT} = 3.0\text{ A}$	$V_F$	–	–	2.0	V
Switch-OFF Thermal Shutdown Hysteresis	$T_{LIM}$ $T_{HYS}$	175 –	– 15	– –	$^\circ\text{C}$
<b>FAULT STATUS <sup>(17)</sup></b>					
Fault Status Leakage Current <sup>(18)</sup> $V_{FS} = 5.0\text{ V}$	$I_{FS(LEAK)}$	–	–	10	$\mu\text{A}$
Fault Status Set Voltage <sup>(19)</sup> $I_{FS} = 300\ \mu\text{A}$	$V_{FS(LOW)}$	–	–	1.0	V

**Notes**

13. Output-ON resistance as measured from output to V+ and ground.
14. Product with date codes of December 2002, week 51, will exhibit the values indicated in this table. Product with earlier date codes may exhibit a minimum of 6.0 A and a maximum of 8.5 A.
15. Outputs switched OFF with D1 or D2.
16. Parameter is guaranteed by design but not production tested.
17. Fault Status output is an open drain output requiring a pull-up resistor to 5.0 V.
18. Fault Status Leakage Current is measured with Fault Status High and *not* set.
19. Fault Status Set Voltage is measured with Fault Status Low and set with  $I_{FS} = 300\ \mu\text{A}$ .

### DYNAMIC ELECTRICAL CHARACTERISTICS

**Table 5. Dynamic Electrical Characteristics**

Characteristics noted under conditions  $5.0\text{ V} \leq V+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ , unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
<b>TIMING CHARACTERISTICS</b>					
PWM Frequency <sup>(20)</sup>	$f_{\text{PWM}}$	–	–	10	kHz
Maximum Switching Frequency During Active Current Limiting <sup>(21)</sup>	$f_{\text{MAX}}$	–	–	20	kHz
Output ON Delay <sup>(22)</sup> V+ = 14 V	$t_{\text{d(ON)}}$	–	–	18	$\mu\text{s}$
Output OFF Delay <sup>(22)</sup> V+ = 14 V	$t_{\text{D(OFF)}}$	–	–	18	$\mu\text{s}$
Output Rise and Fall Time <sup>(23)</sup> V+ = 14 V, $I_{\text{OUT}} = 3.0\text{ A}$	$t_{\text{F}}, t_{\text{R}}$	2.0	5.0	8.0	$\mu\text{s}$
Output Latch-OFF Time	$t_{\text{A}}$	15	20.5	26	$\mu\text{s}$
Output Blanking Time	$t_{\text{B}}$	12	16.5	21	$\mu\text{s}$
Output FET Body Diode Reverse Recovery Time <sup>(24)</sup>	$t_{\text{RR}}$	100	–	–	ns
Disable Delay Time <sup>(25)</sup>	$t_{\text{D(DISABLE)}}$	–	–	8.0	$\mu\text{s}$
Short-circuit/Overtemperature Turn-OFF Time <sup>(26)</sup>	$t_{\text{FAULT}}$	–	4.0	–	$\mu\text{s}$
Power-OFF Delay Time	$t_{\text{POD}}$	–	1.0	5.0	ms

Notes

20. The outputs can be PWM controlled from an external source. This is typically done by holding one input high while applying a PWM pulse train to the other input. The maximum PWM frequency obtainable is a compromise between switching losses and switching frequency. Refer to Typical Switching Waveforms, [Figures 10 through 17](#), pp. [11–12](#).
21. The Maximum Switching Frequency during active current limiting is internally implemented. The internal control produces a constant OFF-time PWM of the output. The output load current effects the Maximum Switching Frequency.
22. Output Delay is the time duration from the midpoint of the IN1 or IN2 input signal to the 10% or 90% point (dependent on the transition direction) of the OUT1 or OUT2 signal. If the output is transitioning High-to-Low, the delay is from the midpoint of the input signal to the 90% point of the output response signal. If the output is transitioning Low-to-High, the delay is from the midpoint of the input signal to the 10% point of the output response signal. See [Figure 4](#), page [9](#).
23. Rise Time is from the 10% to the 90% level and Fall Time is from the 90% to the 10% level of the output signal. See [Figure 6](#), page [9](#).
24. Parameter is guaranteed by design but not production tested.
25. Disable Delay Time is the time duration from the midpoint of the D (disable) input signal to 10% of the output tri-state response. See [Figure 5](#), page [9](#).
26. Increasing currents will become limited at  $I_{\text{LIM}}$ . Hard shorts will breach the  $I_{\text{SCH}}$  or  $I_{\text{SCL}}$  limit, forcing the output into an immediate tri-state latch-OFF. See [Figures 8 and 9](#), page [10](#). Active current limiting will cause junction temperatures to rise. A junction temperature above  $160^\circ\text{C}$  will cause the active current limiting to progressively “fold-back” (or decrease) to 2.5 A typical at  $175^\circ\text{C}$  where thermal latch-OFF will occur. See [Figure 7](#), page [9](#).

### TIMING DIAGRAMS

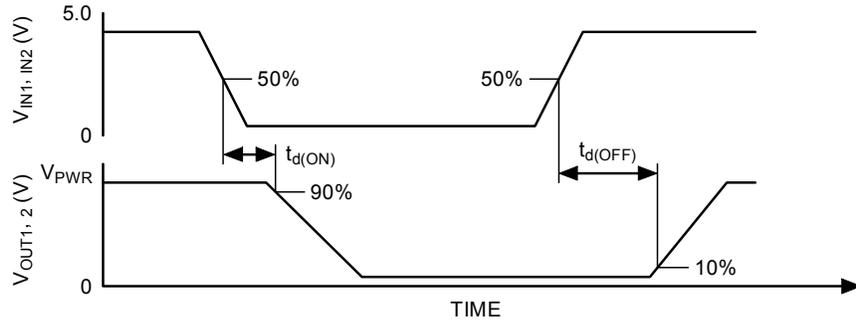


Figure 4. Output Delay Time

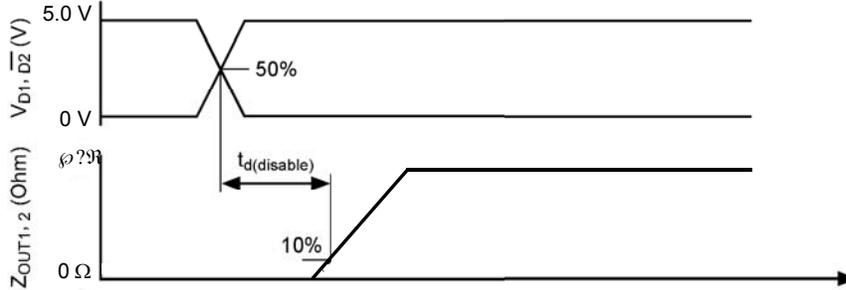


Figure 5. Disable Delay Time

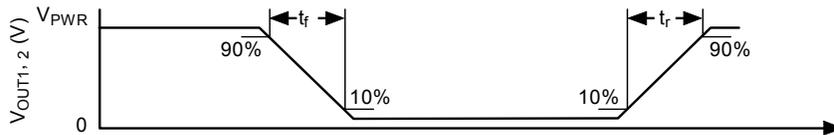


Figure 6. Output Switching Time

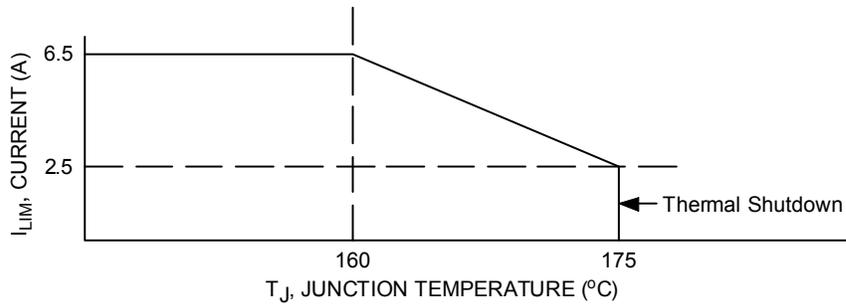


Figure 7. Active Current Limiting Versus Temperature (Typical)

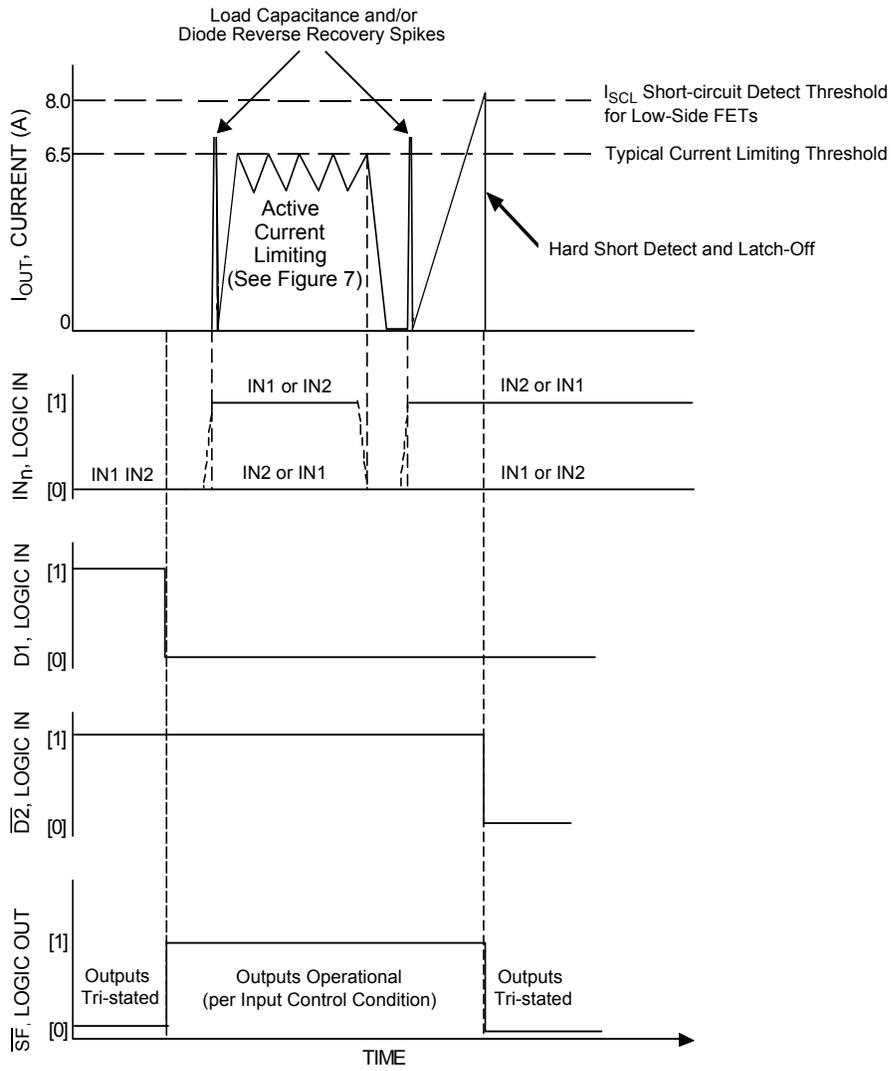


Figure 8. Active Current Limiting Versus Time

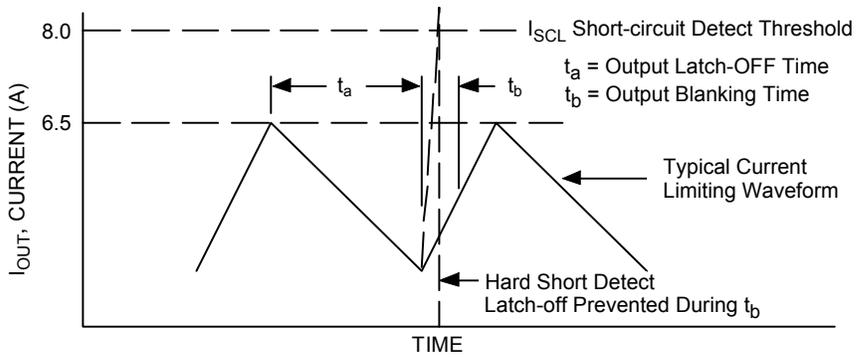
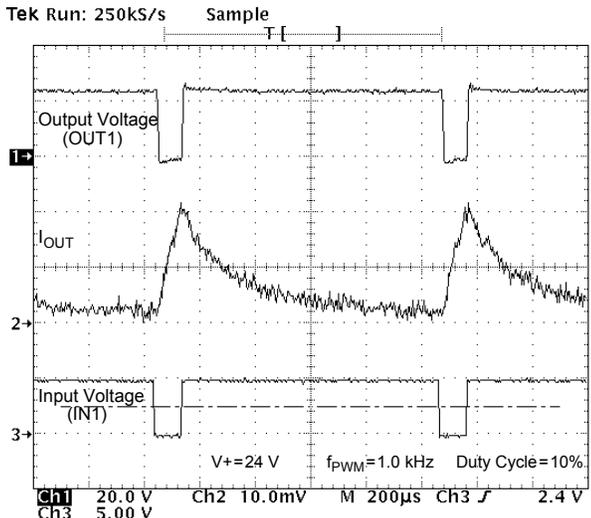


Figure 9. Active Current Limiting Detail

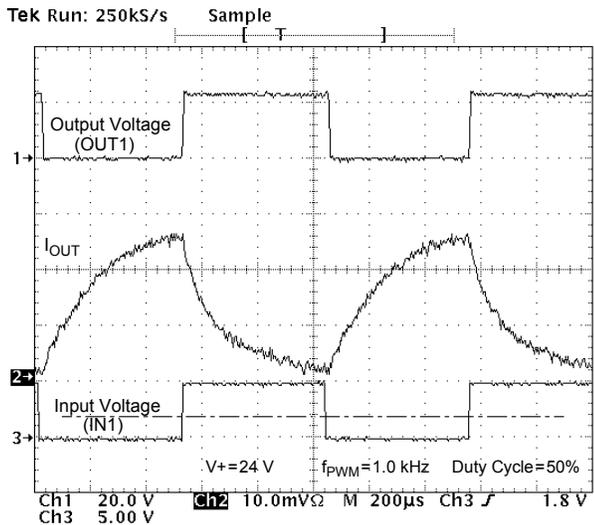
**TYPICAL SWITCHING WAVEFORMS**

**Important** For all plots, the following applies:

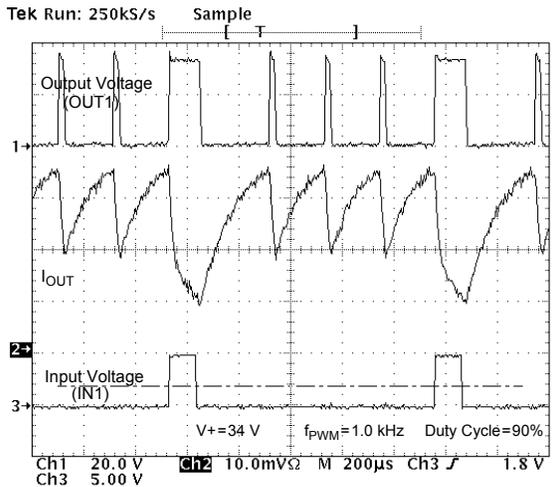
- Ch2=2.0 A per division
- $L_{LOAD}=533 \mu\text{H}$  @ 1.0 kHz
- $L_{LOAD}=530 \mu\text{H}$  @ 10.0 kHz
- $R_{LOAD}=4.0 \Omega$



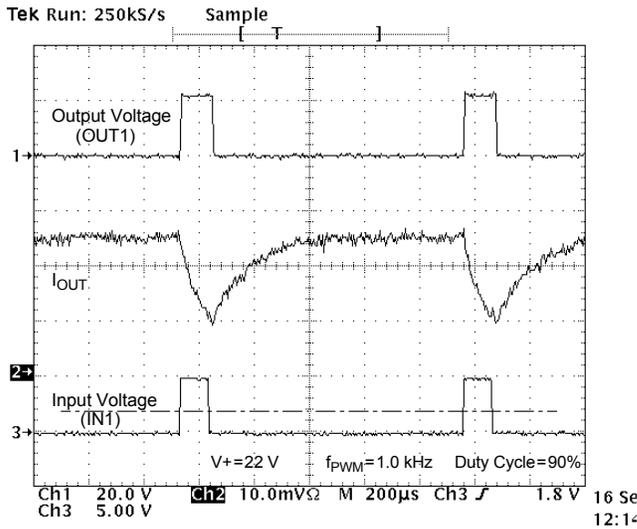
**Figure 10. Output Voltage and Current vs. Input Voltage at V+ = 24 V, PMW Frequency of 1.0 kHz, and Duty Cycle of 10%**



**Figure 11. Output Voltage and Current vs. Input Voltage at V+ = 24 V, PMW Frequency of 1.0 kHz, and Duty Cycle of 50%**



**Figure 12. Output Voltage and Current vs. Input Voltage at V+ = 34 V, PMW Frequency of 1.0 kHz, and Duty Cycle of 90%, Showing Device in Current Limiting Mode**



**Figure 13. Output Voltage and Current vs. Input Voltage at V+ = 22 V, PMW Frequency of 1.0 kHz, and Duty Cycle of 90%**

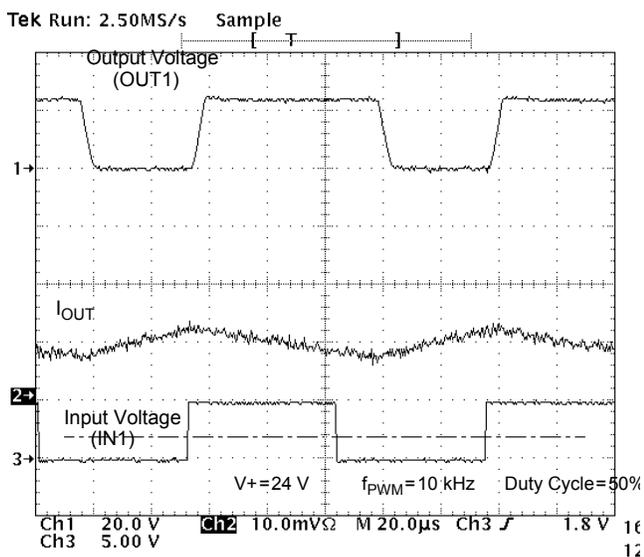


Figure 14. Output Voltage and Current vs. Input Voltage at V<sub>+</sub> = 24 V, PMW Frequency of 10 kHz, and Duty Cycle of 50%

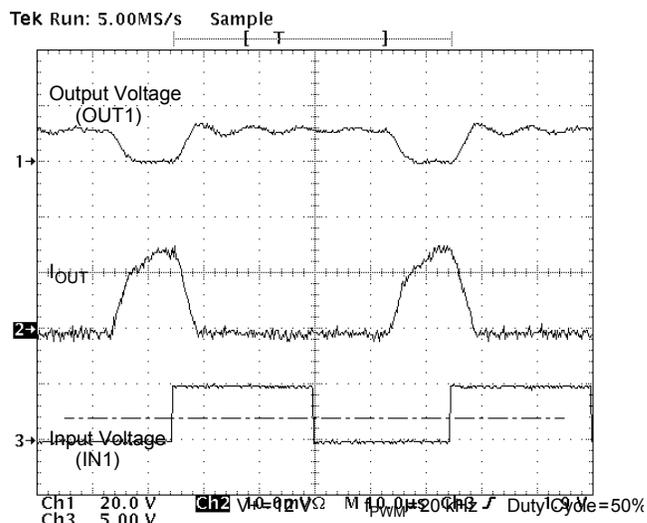


Figure 16. Output Voltage and Current vs. Input Voltage at V<sub>+</sub> = 12 V, PMW Frequency of 20 kHz, and Duty Cycle of 50% for a Purely Resistive Load

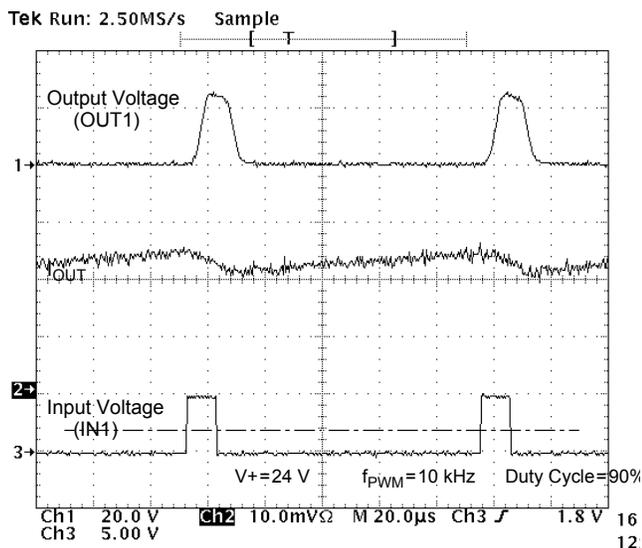


Figure 15. Output Voltage and Current vs. Input Voltage at V<sub>+</sub> = 24 V, PMW Frequency of 10 kHz, and Duty Cycle of 90%

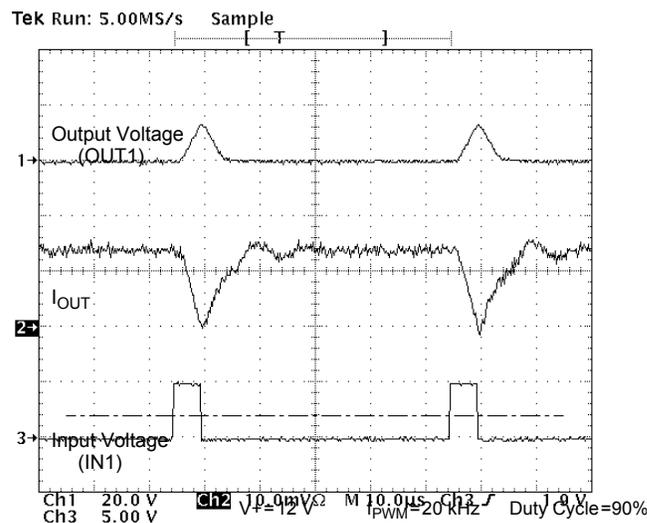


Figure 17. Output Voltage and Current vs. Input Voltage at V<sub>+</sub> = 12 V, PMW Frequency of 20 kHz, and Duty Cycle of 90% for a Purely Resistive Load

**Table 6. Truth Table**

The tri-state conditions and the fault status are reset using D1 or  $\overline{D2}$ . The truth table uses the following notations: L = Low, H = High, X = High or Low, and Z = High-impedance (all output power transistors are switched off).

Device State	Input Conditions				Fault Status Flag	Output States	
	D1	$\overline{D2}$	IN1	IN2	$\overline{FS}$	OUT1	OUT2
Forward	L	H	H	L	H	H	L
Reverse	L	H	L	H	H	L	H
Freewheeling Low	L	H	L	L	H	L	L
Freewheeling High	L	H	H	H	H	H	H
Disable 1 (D1)	H	X	X	X	L	Z	Z
Disable 2 ( $\overline{D2}$ )	X	L	X	X	L	Z	Z
IN1 Disconnected	L	H	Z	X	H	H	X
IN2 Disconnected	L	H	X	Z	H	X	H
D1 Disconnected	Z	X	X	X	L	Z	Z
$\overline{D2}$ Disconnected	X	Z	X	X	L	Z	Z
Undervoltage <sup>(27)</sup>	X	X	X	X	L	Z	Z
Overtemperature <sup>(28)</sup>	X	X	X	X	L	Z	Z
Short Circuit <sup>(28)</sup>	X	X	X	X	L	Z	Z

**Notes**

27. In the case of an undervoltage condition, the outputs tri-state and the fault status is set logic Low. Upon undervoltage recovery, fault status is reset automatically or automatically cleared and the outputs are restored to their original operating condition.
28. When a short-circuit or overtemperature condition is detected, the power outputs are tri-state latched-OFF independent of the input signals and the fault status flag is set logic Low.

### ELECTRICAL PERFORMANCE CURVES

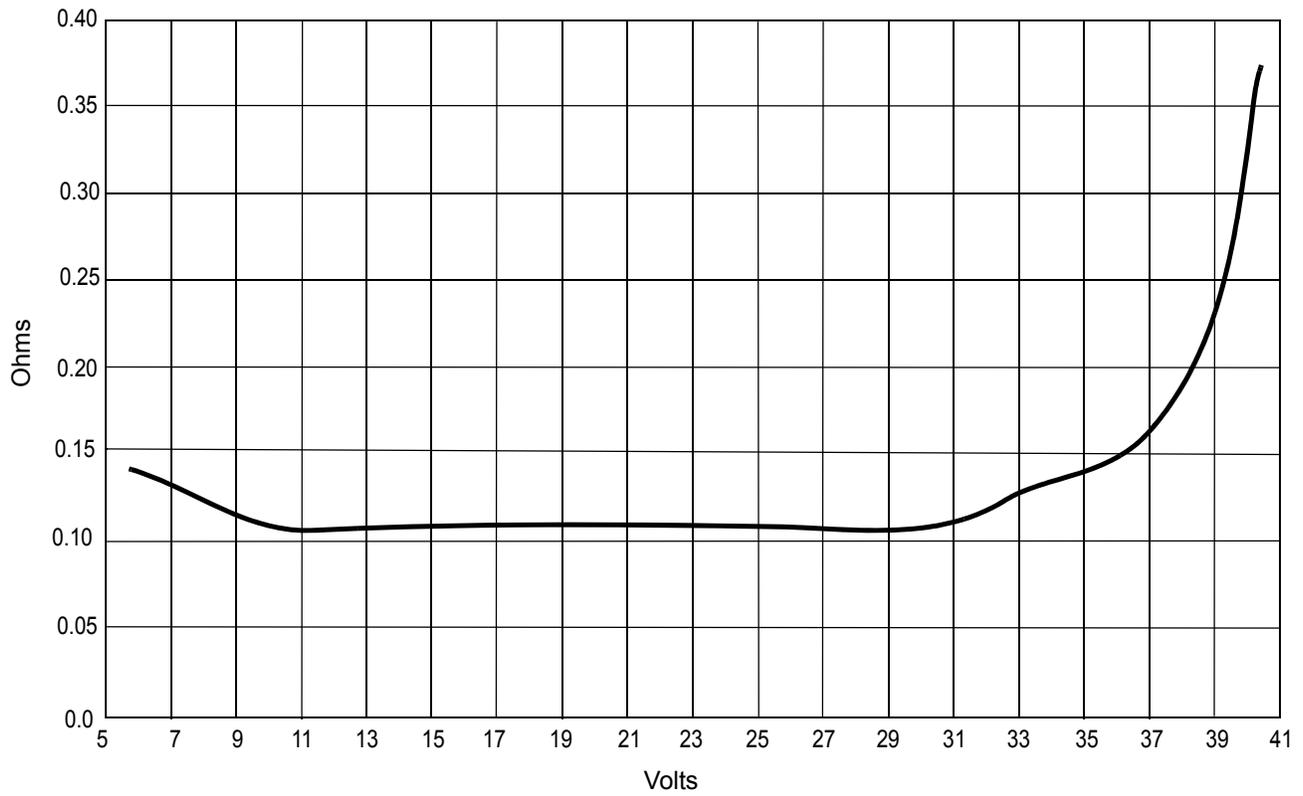


Figure 18. Typical High Side  $R_{DS(ON)}$  Versus  $V+$

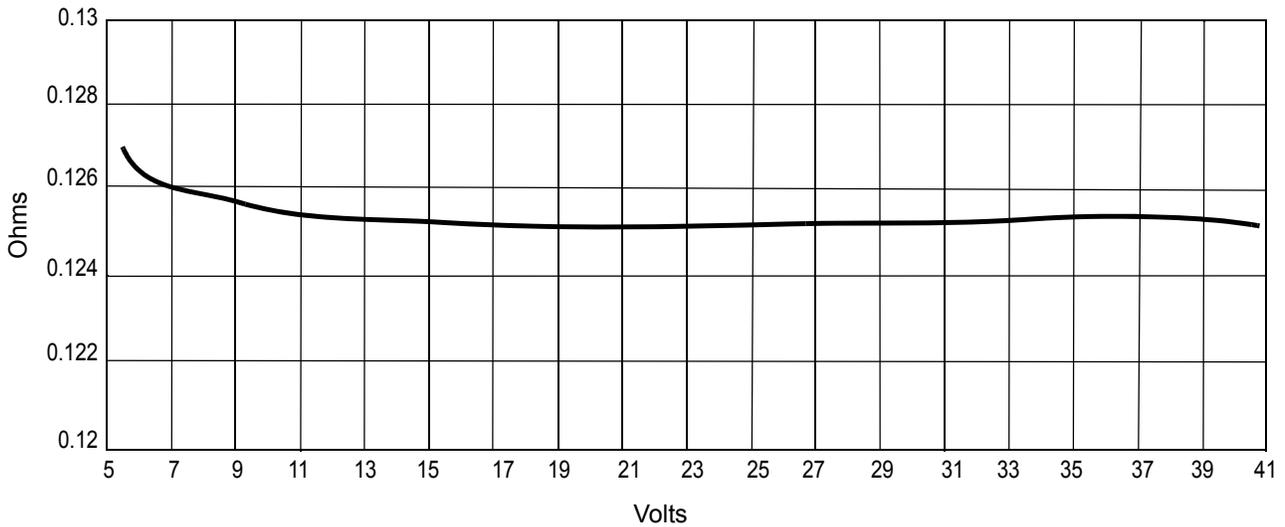


Figure 19. Typical Low Side  $R_{DS(ON)}$  Versus  $V+$

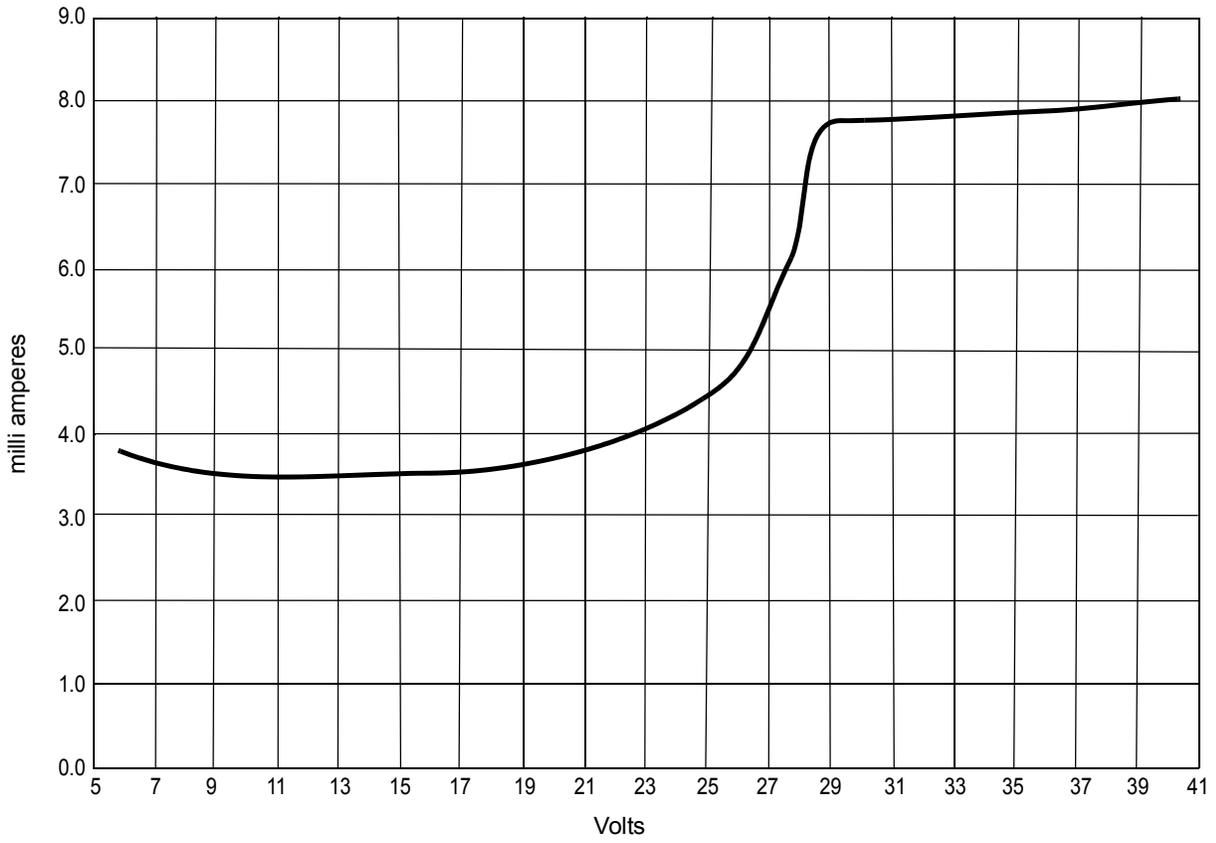


Figure 20. Typical Quiescent Supply Current Versus V+

## FUNCTIONAL DESCRIPTION

### INTRODUCTION

Numerous protection and operational features (speed, torque, direction, dynamic braking, and PWM control), in addition to the 5.0 A current capability, make the 33886 a very attractive, cost-effective solution for controlling a broad range of fractional horsepower DC motors. A pair of 33886 devices can be used to control bipolar stepper motors in both directions. In addition, the 33886 can be used to control permanent magnet solenoids in a push-pull variable force fashion using PWM control. The 33886 can also be used to excite transformer primary windings with a switched square wave to produce secondary winding AC currents.

As shown in [Figure 2](#), Simplified Internal Block Diagram, page [3](#), the 33886 is a fully protected monolithic H-Bridge with Fault Status reporting. For a DC motor to run the input conditions need be as follows: D1 input logic Low,  $\overline{D2}$  input logic High,  $\overline{FS}$  flag cleared (logic High), with one IN logic Low and the other IN logic High to define output polarity. The 33886 can execute dynamic braking by simultaneously turning on either both high side MOSFETs or both low side MOSFETs in the output H-Bridge; e.g., IN1 and IN2 logic High or IN1 and IN2 logic Low.

The 33886 outputs are capable of providing a continuous DC load current of 5.0 A from a 40 V V+ source. An internal charge pump supports PWM frequencies up to 10 kHz. An

external pull-up resistor is required for the open drain  $\overline{FS}$  pin for fault status reporting.

Two independent inputs (IN1 and IN2) provide control of the two totem-pole half-bridge outputs. Two disable inputs (D1 and  $\overline{D2}$ ) are for forcing the H-Bridge outputs to a high-impedance state (all H-Bridge switches OFF).

The 33886 has undervoltage shutdown with automatic recovery, active current limiting, output short-circuit latch-OFF, and overtemperature latch-OFF. An undervoltage shutdown, output short-circuit latch-OFF, or overtemperature latch-OFF fault condition will cause the outputs to turn OFF (i.e., become high-impedance or tri-stated) and the fault output flag to be set Low. Either of the Disable inputs or V+ must be “toggled” to clear the fault flag.

The short-circuit/overtemperature shutdown scheme is unique and best described as using a junction temperature-dependent active current “fold back” protection scheme. When a short-circuit condition is experienced, the current limited output is “ramped down” as the junction temperature increases above 160 °C, until at 175 °C the current has decreased to about 2.5 A. Above 175 °C, overtemperature shutdown (latch-OFF) occurs. This feature allows the device to remain in operation for a longer time with unexpected loads, while still retaining adequate protection for both the device and the load.

### FUNCTIONAL PIN DESCRIPTION

#### POWER/ANALOG GROUNDS (PGND AND AGND)

Power and analog ground pins. The power and analog ground pins should be connected together with a very low-impedance connection.

#### POSITIVE POWER SUPPLY (V+)

V+ pins are the power supply inputs to the device. All V+ pins must be connected together on the printed circuit board with as short as possible traces offering as low-impedance as possible between pins.

V+ pins have an undervoltage threshold. If the supply voltage drops below a V+ undervoltage threshold, the output power stage switches to a tri-state condition and the fault status flag is set and the Fault Status pin voltage switched to a logic Low. When the supply voltage returns to a level that is above the threshold, the power stage automatically resumes normal operation according to the established condition of the input pins and the fault status flag is automatically reset logic High.

#### FAULT STATUS ( $\overline{FS}$ )

This pin is the device fault status output. This output is an active Low open drain structure requiring a pull-up resistor to 5.0 V. Refer to [Table 6, Truth Table](#), page [13](#).

#### LOGIC INPUT 1, 2 AND DISABLE1, 2 (IN1, IN2, D1, AND $\overline{D2}$ )

These pins are input control pins used to control the outputs. These pins are 5.0 V CMOS-compatible inputs with hysteresis. The IN1 and IN2 independently control OUT1 and OUT2, respectively. D1 and  $\overline{D2}$  are complimentary inputs used to tri-state disable the H-Bridge outputs.

When either D1 or  $\overline{D2}$  is set (D1 = logic High or  $\overline{D2}$  = logic Low) in the disable state, outputs OUT1 and OUT2 are both tri-state disabled; however, the rest of the device circuitry is fully operational and the supply  $I_{Q(STANDBY)}$  current is reduced to a few milliamperes. Refer to [Table 6, Truth Table](#), and [Static Electrical Characteristics](#) table, page [6](#).

**H-BRIDGE OUTPUT 1, 2 (OUT1 AND OUT2)**

These pins are the outputs of the H-Bridge with integrated output FET body diodes. The bridge output is controlled using the IN1, IN2, D1, and  $\overline{D2}$  inputs. The outputs have active current limiting above 6.5 A. The outputs also have thermal shutdown (tri-state latch-OFF) with hysteresis as well as short-circuit latch-OFF protection.

A disable timer (time  $t_B$ ) incorporated to detect currents that are higher than active current limit is activated at each output

activation to facilitate detecting hard output short conditions (see [Figure 9](#), page [10](#)).

**CHARGE PUMP CAPACITOR (CCP)**

Charge pump output pin. A filter capacitor (up to 33 nF) can be connected from the  $C_{CP}$  pin and PGND. The device can operate without the external capacitor, although the  $C_{CP}$  capacitor helps to reduce noise and allows the device to perform at maximum speed, timing, and PWM frequency.

## FUNCTIONAL DEVICE OPERATION

### SHORT-CIRCUIT PROTECTION

If an output short-circuit condition is detected, the power outputs tri-state (latch-OFF) independent of the input (IN1 and IN2) states, and the fault status output flag is set logic Low. If the D1 input changes from logic High to logic Low, or if the  $\overline{D2}$  input changes from logic Low to logic High, the output bridge will become operational again and the fault status flag will be reset (cleared) to a logic High state.

The output stage will always switch into the mode defined by the input pins (IN1, IN2, D1, and  $\overline{D2}$ ), provided the device junction temperature is within the specified operating temperature.

### ACTIVE CURRENT LIMITING

The maximum current flow under normal operating conditions is internally limited to  $I_{LIM}$  (5.2 A to 7.8 A). When the maximum current value is reached, the output stages are tri-stated for a fixed time ( $t_a$ ) of 20  $\mu$ s typical. Depending on the time constant associated with the load characteristics, the current decreases during the tri-state duration until the next output ON cycle occurs (see [Figures 9](#) and [12](#), page [10](#) and page [11](#), respectively).

The current limiting threshold value is dependent upon the device junction temperature. When  $-40\text{ }^\circ\text{C} < T_J < 160\text{ }^\circ\text{C}$ ,  $I_{LIM}$  is between 5.2 A and 7.8 A. When  $T_J$  exceeds  $160\text{ }^\circ\text{C}$ , the  $I_{LIM}$  current decreases linearly down to 2.5 A typical at  $175\text{ }^\circ\text{C}$ . Above  $175\text{ }^\circ\text{C}$  the device overtemperature circuit detects  $T_{LIM}$  and overtemperature shutdown occurs (see [Figure 7](#), page [9](#)). This feature allows the device to remain

operational for a longer time but at a regressing output performance level at junction temperatures above  $160\text{ }^\circ\text{C}$ .

### OVERTEMPERATURE SHUTDOWN AND HYSTERESIS

If an overtemperature condition occurs, the power outputs are tri-state (latched-OFF) independent of the input signals and the fault status flag is set logic Low.

To reset from this condition, D1 must change from logic High to logic Low, or  $\overline{D2}$  must change from logic Low to logic High. When reset, the output stage switches ON again, provided that the junction temperature is now below the overtemperature threshold limit minus the hysteresis.

**Note** Resetting from the fault condition will clear the fault status flag.

### MAIN DIFFERENCES COMPARED TO MC33186DH1

- COD pin has been removed. Pin 8 is now a Do Not Connect (DNC) pin.
- Pin 20 is no longer connected in the 20 HSOP package. It is now a DNC pin.
- $R_{DS(ON)}$  max at  $T_J = 150\text{ }^\circ\text{C}$  is now 225 m $\Omega$  per each output transistor.
- Maximum temperature operation is now  $160\text{ }^\circ\text{C}$ , as minimum thermal shutdown temperature has increased.
- Current regulation limiting foldback is implemented above  $160\text{ }^\circ\text{C}$   $T_J$ .
- Thermal resistance junction to case has been increased from  $\sim 2.0\text{ }^\circ\text{C/W}$  to  $\sim 5.0\text{ }^\circ\text{C/W}$ .

## PERFORMANCE

The 33886 is designed for enhanced thermal performance. The significant feature of this device is the exposed copper pad on which the power die is soldered. This pad is soldered on a PCB to provide heat flow to ambient and also to provide thermal capacitance. The more copper area on the PCB, the better the power dissipation and transient behavior will be.

**Example** Characterization on a double-sided PCB: bottom side area of copper is 7.8 cm<sup>2</sup>; top surface is 2.7 cm<sup>2</sup> (see [Figure 21](#)); grid array of 24 vias 0.3 mm in diameter.

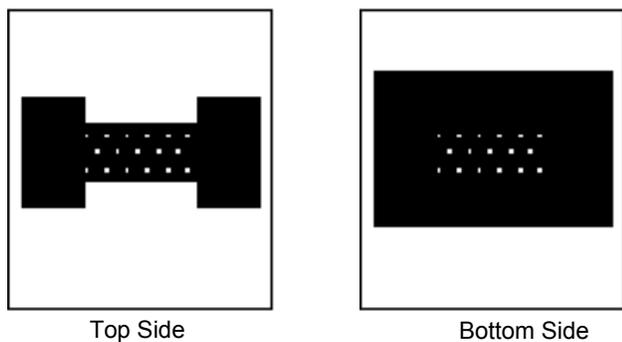


Figure 21. PCB Test Layout

[Figure 22](#) shows the thermal response with the device soldered on to the test PCB described in [Figure 21](#).

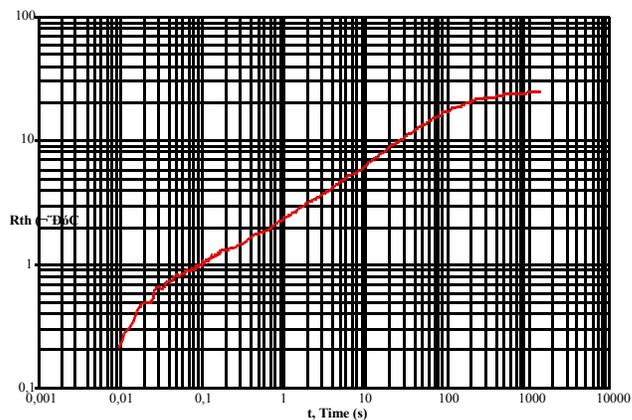


Figure 22. 33886 Thermal Response

## TYPICAL APPLICATIONS

A typical application schematic is shown in [Figure 23](#). For precision high-current applications in harsh, noisy

environments, the V+ by-pass capacitor may need to be substantially larger.

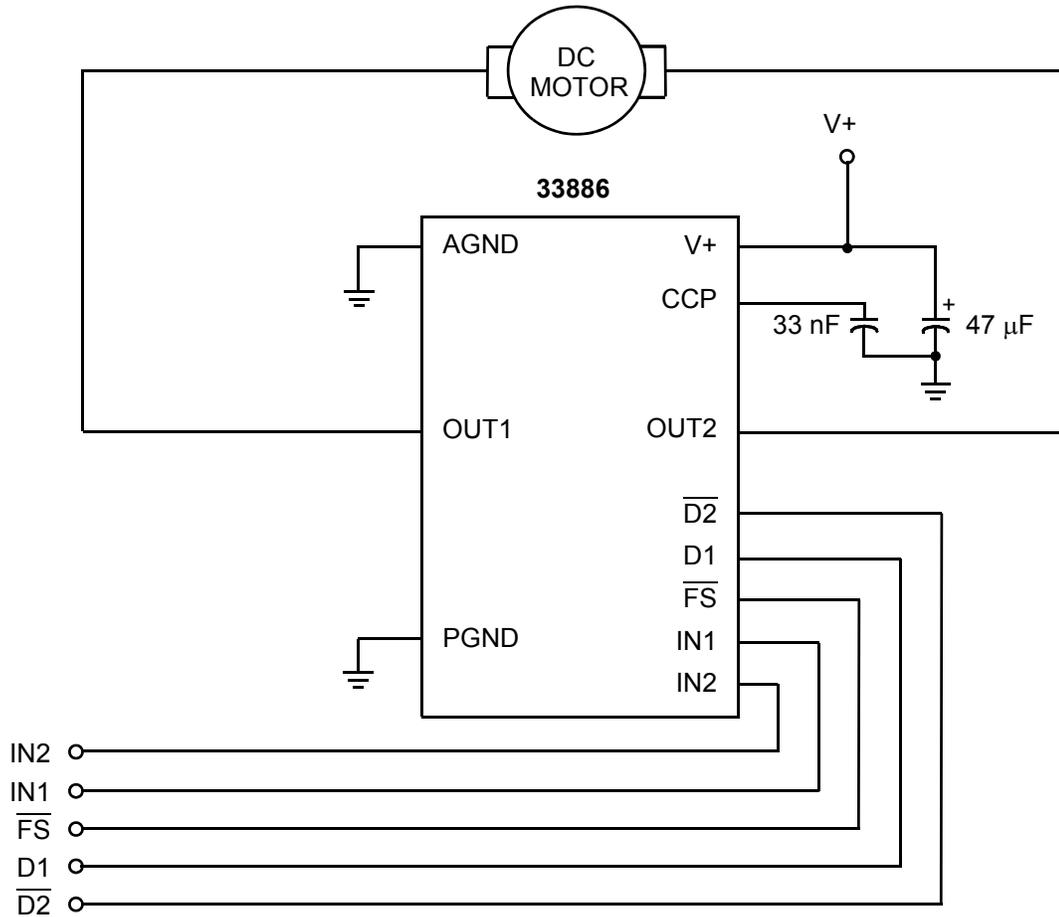
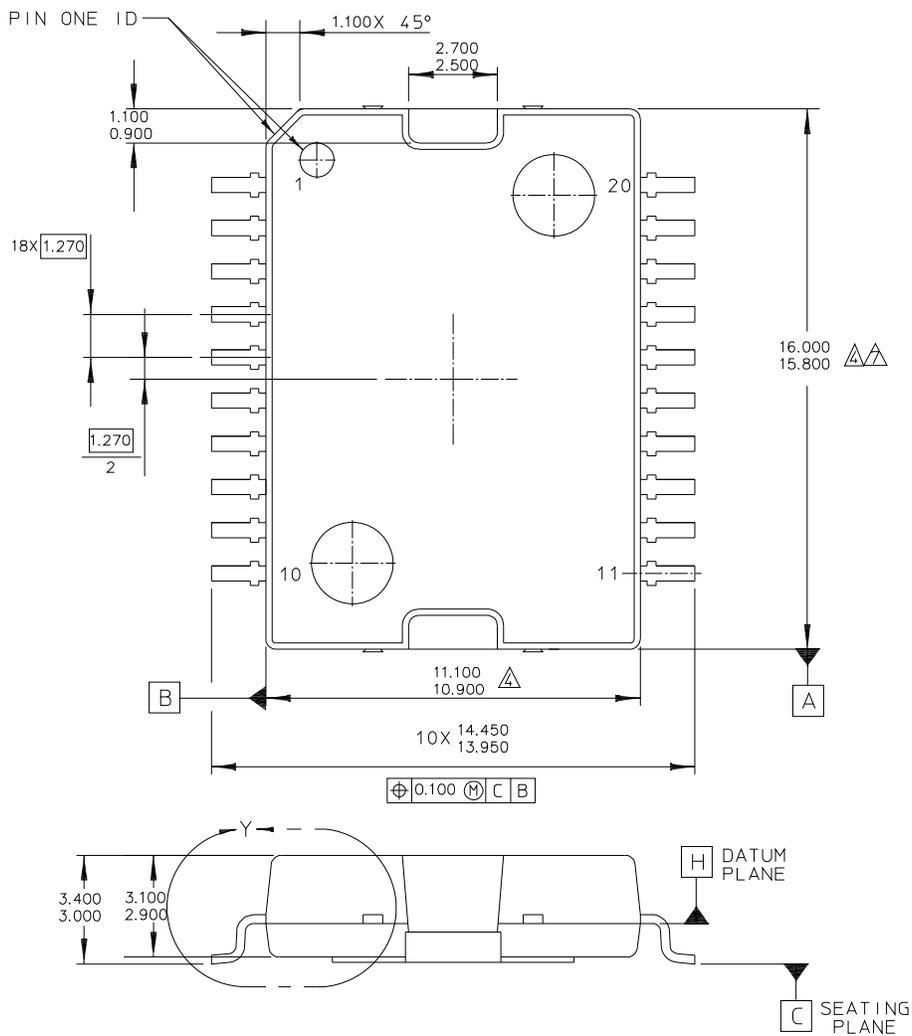


Figure 23. 33886 Typical Application Schematic

# PACKAGING

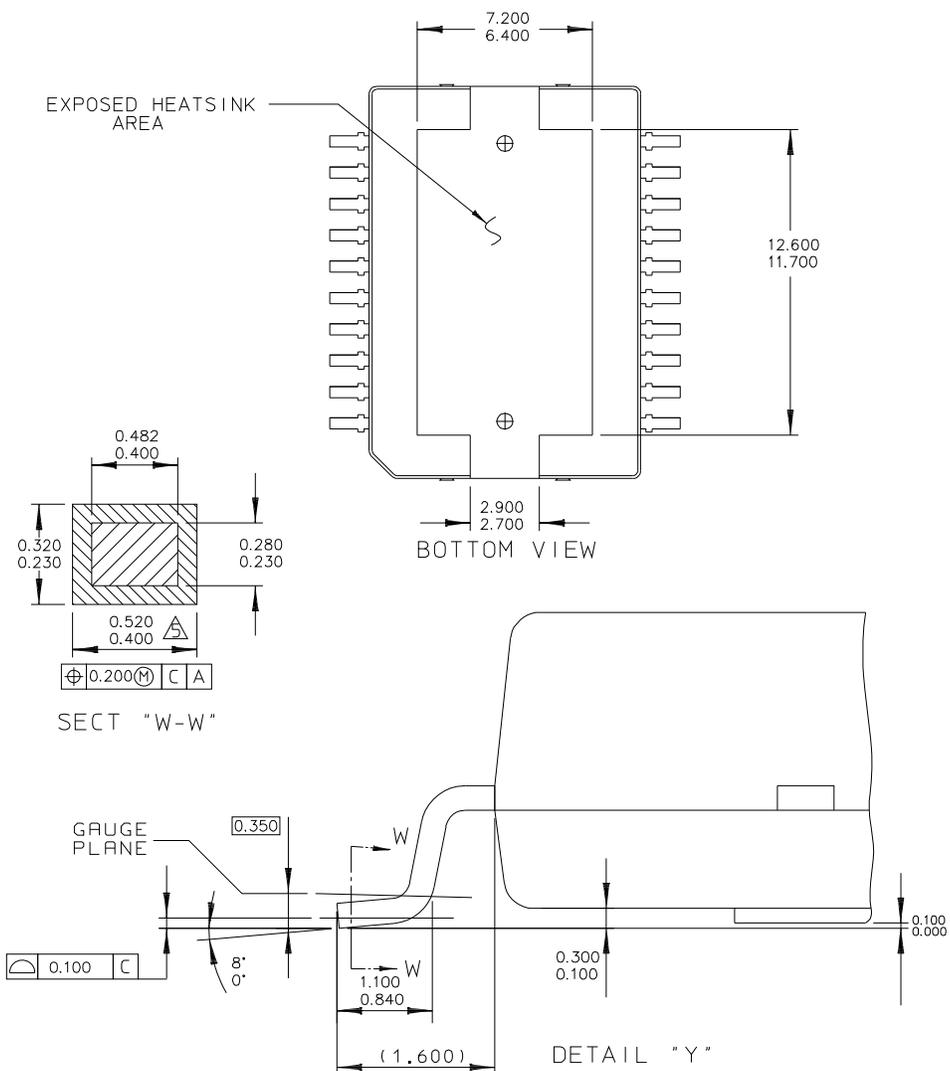
## PACKAGE DIMENSIONS

**Important** For the most current revision of the package, visit [www.freescale.com](http://www.freescale.com) and perform a keyword search on **98ASH70702A** listed.



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TITLE: 20 LEAD HSOP W/PROTRUDING HEATSINK	DOCUMENT NO: 98ASH70702A	REV: B	
	CASE NUMBER: 979	11 OCT 2005	
	STANDARD: NON-JEDEC		

**VW (Pb-FREE) SUFFIX**  
20-PIN HSOP  
98ASH70702A  
ISSUE B



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NOTES:

1. CONTROLLING DIMENSION: MILLIMETER
2. DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE H IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
4. THIS DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.150 PER SIDE. DIMENSIONS DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
5. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS A AND B TO BE DETERMINED AT DATUM PLANE H.
7. DIMENSIONS DOES NOT INCLUDE TIEBAR PROTRUSIONS. ALLOWABLE TIEBAR PROTRUSIONS ARE 0.150 PER SIDE.

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## 5.0 A H-BRIDGE

### THERMAL ADDENDUM - REVISION 2.0

#### Introduction

This thermal addendum is provided as a supplement to the MC33186 technical data sheet. The addendum provides thermal performance information that may be critical in the design and development of system applications. All electrical, application, and packaging information is provided in the data sheet.

#### Packaging and Thermal Considerations

The MC33186 is offered in a 20 pin HSOP exposed pad, single die package. There is a single heat source (P), a single junction temperature (T<sub>J</sub>), and thermal resistance (R<sub>θJA</sub>).

$$\{ T_J \} = [ R_{\theta JA} ] \cdot \{ P \}$$

The stated values are solely for a thermal performance comparison of one package to another in a standardized environment. This methodology is not meant to and will not predict the performance of a package in an application-specific environment. Stated values were obtained by measurement and simulation according to the standards listed below.

#### Standards

Table 7. Thermal Performance Comparison

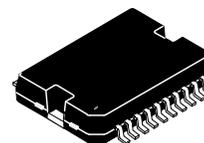
Thermal Resistance	[°C/W]
R <sub>θJA</sub> <sup>(1)(2)</sup>	20
R <sub>θJB</sub> <sup>(2)(3)</sup>	6.0
R <sub>θJA</sub> <sup>(1)(4)</sup>	52
R <sub>θJC</sub> <sup>(5)</sup>	1.0

#### NOTES:

1. Per JEDEC JESD51-2 at natural convection, still air condition.
2. 2s2p thermal test board per JEDEC JESD51-5 and JESD51-7.
3. Per JEDEC JESD51-8, with the board temperature on the center trace near the center lead.
4. Single layer thermal test board per JEDEC JESD51-3 and JESD51-5.
5. Thermal resistance between the die junction and the exposed pad surface; cold plate attached to the package bottom side, remaining surfaces insulated.

33886HSOP

20-PIN HSOP-EP



VW (Pb-FREE) SUFFIX  
98ASH70702A  
20-PIN HSOP-EP

**Note** For package dimensions, refer to the 33886 device data sheet.

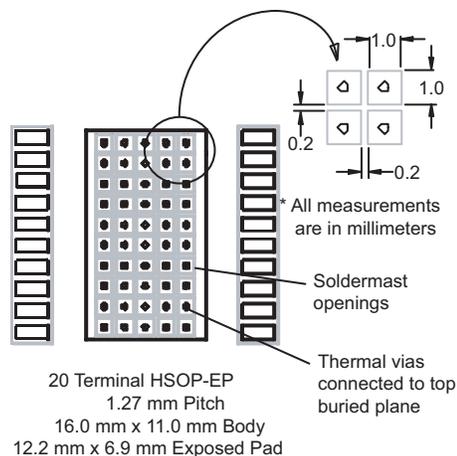


Figure 24. Thermal Land Pattern for Direct Thermal Attachment According to JESD51-5

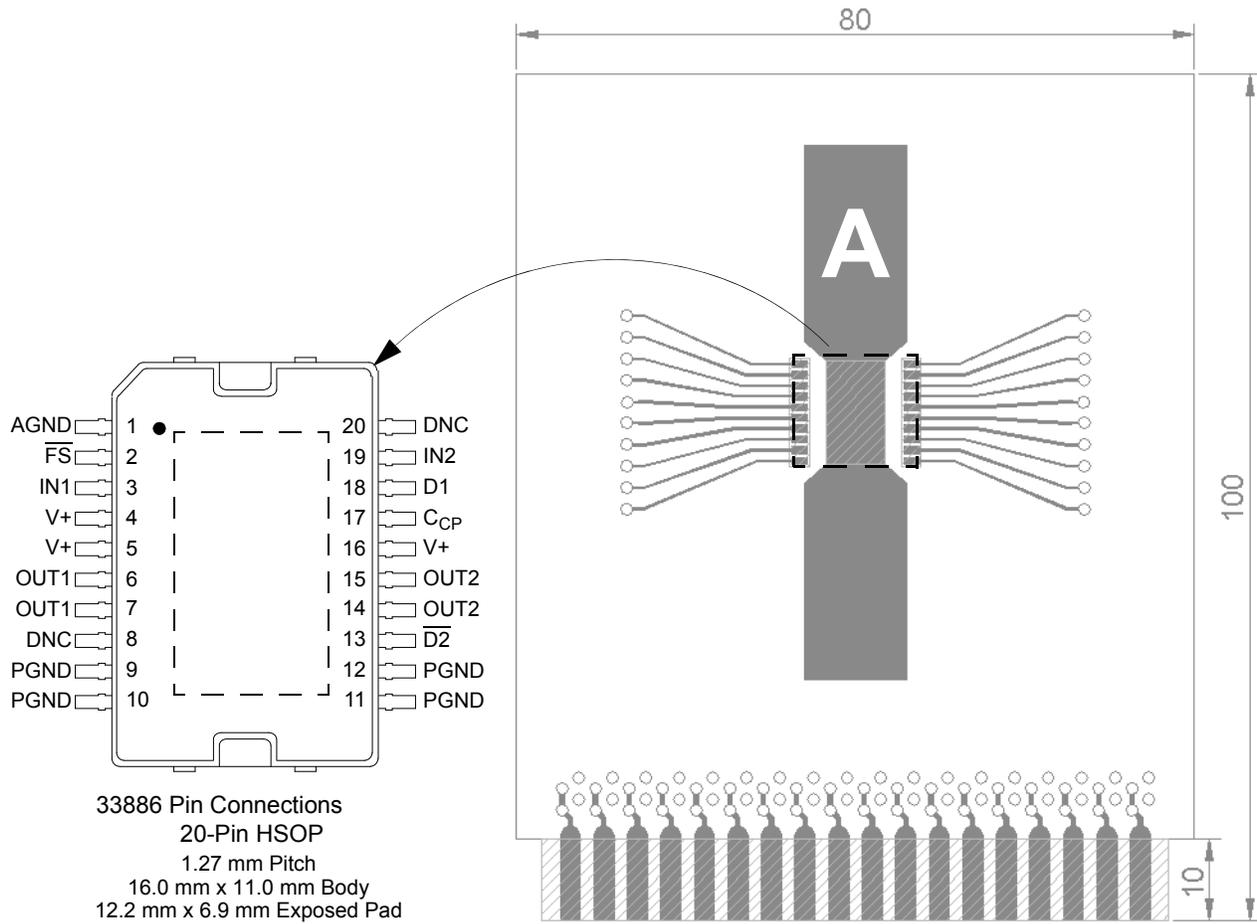


Figure 25. Thermal Test Board

**Device on Thermal Test Board**

- Material: Single layer printed circuit board  
FR4, 1.6 mm thickness  
Cu traces, 0.07 mm thickness
- Outline: 80 mm x 100 mm board area,  
including edge connector for thermal testing
- Area A: Cu heat-spreading areas on board surface
- Ambient Conditions: Natural convection, still air

**Table 8. Thermal Resistance Performance**

Thermal Resistance	Area A (mm <sup>2</sup> )	°C/W
$R_{\theta JA}$	0.0	52
	300	36
	600	32
$R_{\theta JS}$	0.0	10
	300	7.0
	600	6.0

$R_{\theta JA}$  is the thermal resistance between die junction and ambient air.

$R_{\theta JS}$  is the thermal resistance between die junction and the reference location on the board surface near a center lead of the package (see [Figure 25](#)).

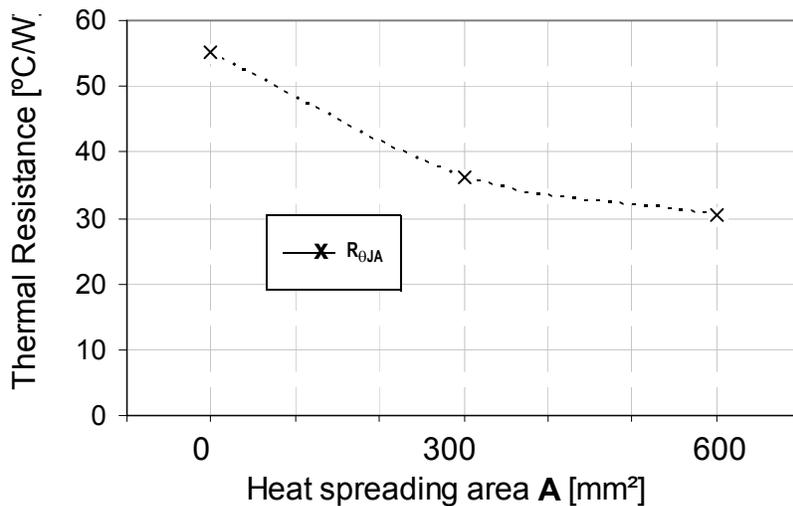


Figure 26. Device on Thermal Test Board  $R_{\theta JA}$

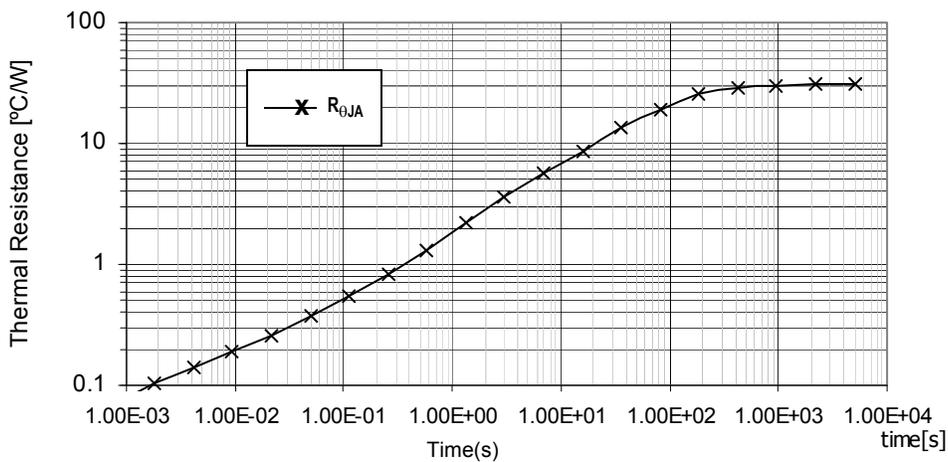


Figure 27. Transient Thermal Resistance  $R_{\theta JA}$   
Device on Thermal Test Board Area A = 600 (mm<sup>2</sup>)

## REVISION HISTORY

Revision	Date	Description of Changes
7.0	7/2005	<ul style="list-style-type: none"> <li>• Implemented Revision History page</li> <li>• Added Thermal Addendum</li> <li>• Converted to Freescale format</li> </ul>
8.0	2/2007	<ul style="list-style-type: none"> <li>• Updated data sheet format</li> <li>• Removed Peak Package Reflow Temperature During Reflow (solder reflow) parameter from <a href="#">Maximum Ratings on page 5</a>. Added note with instructions to obtain this information from <a href="http://www.freescale.com">www.freescale.com</a>.</li> </ul>
9.0	3/2011	<ul style="list-style-type: none"> <li>• Removed part number MC33886VW/R2 and added part number MC33886PVW/R2 to the ordering Information on page 1.</li> <li>• Updated package drawing.</li> <li>• Removed all DH package information.</li> <li>• Updated form and style</li> </ul>
10.0	01/2014	<ul style="list-style-type: none"> <li>• No technical changes. Revised back page. Updated document properties. Added SMARTMOS sentence to last paragraph.</li> </ul>

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